

Notice of References Cited	Application/Control No. 10/774,213		Applicant(s)/Patent Under Reexamination HIRANO ET AL.	
	Examiner George A. Goudreau		Art Unit 1763	Page 1 of 1

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*	C	US-6,368,913	04-2002	Yamamoto, Ichiro	438/255
*	D	US-6,413,833	07-2002	Yamamoto, Ichiro	438/398
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.